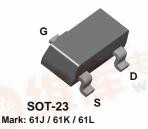


PN4091 PN4092 PN4093 MMBF4091 MMBF4092 MMBF4093





NOTE: Source & Drain are interchangeable

## **N-Channel Switch**

This device is designed for low level analog switching, sample and hold circuits and chopper stabalized amplifiers. Sourced from Process 51. See J111 for characteristics.

## Absolute Maximum Ratings\* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{DG}$	Drain-Gate Voltage	40	V
V <sub>GS</sub>	Gate-Source Voltage	- 40	V
I <sub>GF</sub>	Forward Gate Current	50	mA
T <sub>J</sub> ,T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

### Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max		Units
	7 7 7 1 7 1 7 1 7 1 7 1 7 1 7 1	PN4091-4093	*MMBF4091-4093	1
P <sub>D</sub>	Total Device Dissipation	625	350	mW
	Derate above 25°C	5.0	2.8	mW/°C
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."



# **N-Channel Switch**

(continued)

Symbol	Parameter	Test Conditions	8	Min	Max	Units
OFF CHAF	RACTERISTICS					
V <sub>(BR)GSS</sub>	Gate-Source Breakdown Voltage	$I_G = 1.0  \mu A,  V_{DS} = 0$		- 40		V
V <sub>GS(off)</sub>	Gate-Source Cutoff Voltage	V <sub>DS</sub> = 20 V, I <sub>D</sub> = 1.0 nA	4091	- 5.0	- 10	V
			4092	- 2.0	- 7.0	V
	Drain Cata Laglage Current	V 20 V I 0	4093	- 1.0	- 5.0 - 200	V
$I_{DGO}$	Drain-Gate Leakage Current	$V_{DG} = 20 \text{ V}, I_S = 0$ $V_{DG} = 20 \text{ V}, I_S = 0, T_A = 150$	0°C		- 400	pA nA
I <sub>D(off)</sub>	Drain Cutoff Leakage Current	$V_{DS} = 20 \text{ V}, V_{GS} = -12 \text{ V}$	4091		200	pA
5(0.1)		$V_{DS} = 20 \text{ V}, V_{GS} = -8.0 \text{ V}$	4092		200	рA
		$V_{DS} = 20 \text{ V}, V_{GS} = -6.0 \text{ V}$	4093		200	pA
		$V_{DS} = 20 \text{ V}, V_{GS} = -12 \text{ V},$ $T_A = 150^{\circ}\text{C}$	4091		400	nA
		$V_{DS} = 20 \text{ V}, V_{GS} = -8.0 \text{ V},$	4031			
		T <sub>A</sub> = 150°C	4092		400	nA
		$V_{DS} = 20 \text{ V}, V_{GS} = -6.0 \text{ V},$			400	^
		T <sub>A</sub> = 150°C	4093		400	nA
I <sub>DSS</sub>	Zero-Gate Voltage Drain Current*	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0	4091 4092 4093	30 15 8.0		mA mA mA
\ /	Drain Course On Voltage	$I_D = 6.6 \text{ mA}, V_{GS} = 0$	4093 4091	8.0	0.2	MA V
V <sub>DS(on)</sub>	Drain-Source On Voltage	$I_D = 0.0 \text{ mA}, V_{GS} = 0$ $I_D = 4.0 \text{ mA}, V_{GS} = 0$	4092		0.2	v
		$I_D = 2.5 \text{ mA}, V_{GS} = 0$	4093		0.2	V
r <sub>DS(on)</sub>	Drain-Source On Resistance	$I_D = 1.0 \text{ mA}, V_{GS} = 0$	4091		30	Ω
			4092		50	Ω
			4093		80	Ω
SMALL-SI	GNAL CHARACTERISTICS					
r <sub>ds(on)</sub>	Drain-Source On Resistance	$V_{DS} = V_{GS} = 0$ , f= 1.0 kHz	4091		30	Ω
			4092 4093		50 80	Ω
Ciss	Input Capacitance	V <sub>DS</sub> = 20, V <sub>GS</sub> = 0, f = 1.0 M			16	Ω pF
Crss	Reverse Transfer Capacitance	V <sub>GS</sub> = - 20 V, f = 1.0 MHz			5.0	pF
Olss	1	100 20 1,1 110 1111 12				<u> </u>
SWITCHII	NG CHARACTERISTICS					
t <sub>on</sub>	Turn-On Time	I <sub>D(on)</sub> = 12 mA	4091		25	ns
		$I_{D(on)} = 6.0 \text{ mA}$	4092		35	ns
		$I_{D(on)} = 3.0 \text{ mA}$	4093		60	ns
t <sub>off</sub>	Turn-Off Time	$V_{GS(off)} = 12 V$	4091		40	ns
		$V_{GS(off)} = 6.0 \text{ V}$ $V_{GS(off)} = 3.0 \text{ V}$	4092		60 80	ns ns
			4093		· OU	

<sup>\*</sup>Pulse Test: Pulse Width  $\leq\!300~\mu\text{s}$  , Duty Cycle  $\leq\!1.0\%$ 

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